

# PROCEEDINGS OF SPIE

## **Semiconductor Lasers and Laser Dynamics III**

**Krassimir P. Panajotov**

**Marc Sciamanna**

**Angel A. Valle**

**Rainer Michalzik**

*Editors*

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- 5 Optical Injection and Dynamics  
**Marc Sciamanna**, Supèlec (France)
- 6 Semiconductor Lasers II  
**André Strittmatter**, Technische Universität Berlin (Germany)
- 7 VCSELs and Micro-Optics: Joint Session with Conference 6992  
**Rainer Michalzik**, Universität Ulm (Germany)
- 8 Vertical Cavity Lasers  
**Krassimir P. Panajotov**, Vrije Universiteit Brussel (Belgium) and Institute of Solid State Physics (Bulgaria)
- 9 Ring Lasers  
**Athanasios T. Gavrielides**, Air Force Research Laboratory (USA)
- 10 Semiconductor Lasers III  
**Ortwin G. Hess**, University of Surrey (United Kingdom)